

AS4C512M16D3LC-10BIN vs MT41K512M16VRP-107IT:P Comparison

Part Number & result Parameter	AS4C512M16D3LC-12BIN (Alliance Memory Rev.C)	MT41K512M16VRP-107IT:P (Micron Part)	Comparison Result
Product Description	DDR3L SDRAM	DDR3L SDRAM	Same
Die in Package	Dual Die Part	Dual Die Part	
Density/Memory Size	8Gb	8Gb	Same
Memory Organization	64Mb x 16 IOs x 8 banks	64Mb x 16 IOs x 8 banks	Same
Data Bus Width	16 bits	16 bits	Same
Row / Column Address	A[15:0] / A[9:0]	A[15:0] / A[9:0]	Same
Page Size	2KB	2KB	Same
Operating PowerSupply	VDD/Q=1.35V (1.283~1.45V)	VDD/Q=1.35V (1.283~1.45V)	Same
DDR3 Compatibility	Yes backward compatible to DDR3 (VDD/Q= 1.425V ~1.575V)		Same
Operating Temperature	Industrial (-40°C ≤ Tc ≤ +95°C)	Industrial (-40°C ≤ Tc ≤ +95°C)	Same
Clock Frequency	933 MHz	933 MHz	Same
Max Data Rate (MT/s)	1866 Mbps	1866 Mbps	Same
tRCD/tRP (ns)	13.91	13.91	Same
CL	13	13	Same
I/O Capacitance	CIO :2.1pF Max	CIO : 4.2pF Max	Different
Pin to Pin Compatible	Yes	Yes	Same
AC/DC Characteristics	Same	Same	Meet JEDEC
IDD Specification			
IDD Spec conditions	-40C to 95C	-40C to 95C	
IDD0 (mA)	96	58	Micron better
IDD1 (mA)	125	88	Micron better
IDD2P0 (mA)	16	22	Alliance better
IDD2P1 (mA)	30	22	Micron better
IDD2N (mA)	50	34	Micron better
IDD2Q (mA)	50	30	Micron better
IDD3P (mA)	54	30	Micron better
IDD3N (mA)	62	42	Micron better
IDD4R (mA)	200	180	Micron better
IDD4W (mA)	360	180	Micron better
IDD5B (mA)	477	304	Micron better
IDD6 (mA)	24	30	Alliance better
IDD6ET (mA)	32	46	Alliance better
IDD7 (mA)	270	292	Alliance better
IDD8 (mA)	20	26	Alliance better
Package Dimension	96b FBGA (9 x 13 x 1.2mm)	96b FBGA (8 x 14 x 1.2mm)	Different
Package Ball Matrix	12 x 6.4 x 0.8mm	12 x 6.4 x 0.8mm	Same
Pb & Halogen Free	Yes	Yes	Same